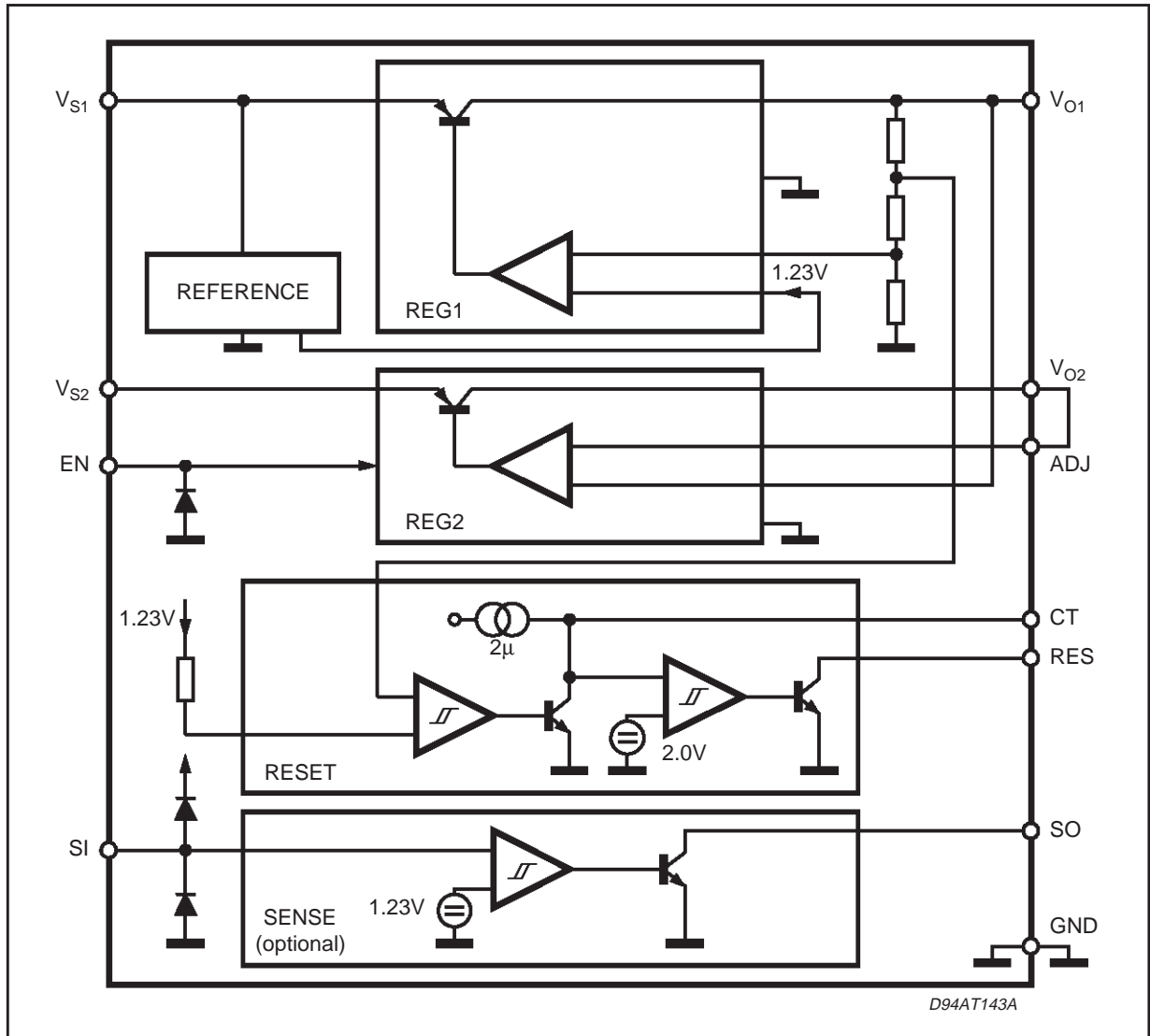


BLOCK DIAGRAM



THERMAL DATA

| Symbol | Parameter | | Powerdip | PowerSO20 | SO20 | Unit |
|-----------------------|-------------------------------------|------|----------|-----------|------|------|
| R _{thj-case} | Thermal Resistance Junction-Case | Max. | 14 | < 2 | - | °C/W |
| R _{thj-amb} | Thermal Resistance Junction-Ambient | Max. | 90 | - | 20 | °C/W |

L4938N - L4938ND - L4938NPD

ELECTRICAL CHARACTERISTICS ($V_S = 14V$; $-40^\circ C \leq T_J \leq 125^\circ C$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-------------------|--|---|----------|------------|-------------|--------------------|
| V_S | Operating Supply Voltage | | | | 25 | V |
| V_{O1} | Standby Output Voltage | $6V \leq V_S \leq 25V$ $1mA \leq I_{O1} \leq 50mA$ | 4.90 | 5.00 | 5.10 | V |
| $V_{O2} - V_{O1}$ | Output Voltage 2 Tracking Error (note 1) | $6V \leq V_S \leq 25V$ $5mA \leq I_{O2} \leq 500mA$ Enable = LOW | -25 | | +25 | mV |
| I_{ADJ} | ADJ Input Current | $I_{O1} = 1mA$; $I_{O2} = 5mA$ | -1 | 0.1 | 1 | μA |
| V_{DP1} | Dropout Voltage 1 | $I_{O1} = 10mA$ $I_{O1} = 50mA$ | | 0.1 0.2 | 0.25 0.4 | V V |
| V_{IO1} | Input to Output Voltage Difference in Undervoltage Condition | $V_S = 4V$, $I_{O1} = 35mA$ | | | 0.4 | V |
| V_{DP2} | Dropout Voltage 2 | $I_{O1} = 100mA$ $I_{O1} = 500mA$ | | 0.2 0.3 | 0.3 0.6 | V V |
| V_{IO2} | Input to Output Voltage Difference in Undervoltage Condition | $V_S = 4.6V$, $I_{O1} = 350mA$ | | | 0.6 | V |
| $V_{OL1,2}$ | Line Regulation | $6V \leq V_S \leq 25V$ $I_{O1} = 1mA$; $I_{O2} = 5mA$ | | | 20 | mV |
| V_{OLO1} | Load Regulation 1 | $1mA \leq I_{O1} \leq 50mA$ | | | 25 | mV |
| V_{OLO2} | Load Regulation 2 | $5mA \leq I_{O2} \leq 500mA$ | | | 50 | mV |
| I_{LIM1} | Current Limit 1 | $V_{O1} = 4.5V$ $V_{O1} = 0V$ (note 2) | 55 25 | 100 50 | 200 100 | mA mA |
| I_{LIM2} | Current Limit 2 | $V_{O2} = 0V$ | 550 | 1000 | 1700 | mA |
| I_{QSB} | Quiescent Current Standby Mode (output 2 disabled) | $I_{O1} = 0.3mA$; $T_J < 100^\circ C$ $V_{EN} \geq 2.4V$ $V_S = 14V$ $V_S = 3.5V$ | | 210 340 | 290 850 | μA μA |
| I_Q | Quiescent Current | $I_{O1} = 50mA$ $I_{O1} = 500mA$ | | | 30 | mA |

ENABLE

| | | | | | | |
|--------------|--|--|-----------|-----------|------------|--------------------|
| V_{ENL} | Enable Input LOW Voltage (output 2 active) | | -0.3 | | 1.5 | V |
| V_{ENH} | Enable Input HIGH Voltage | | 2.4 | | 7 | V |
| V_{ENhyst} | Enable Hysteresis | | 30 | 75 | 200 | mV |
| I_{EN} | Enable Input Current | $0V < V_{EN} < 1.2V$ $2.5V < V_{EN} < 7V$ | -10 -1 | -1.5 0 | -0.5 +1 | μA μA |

ELECTRICAL CHARACTERISTICS (continued)**RESET**

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------------|---------------------------------------|---|----------------------|------|----------------------|------|
| V _{Rt} | Reset Low Threshold Voltage | | V _{O1} -0.4 | 4.7 | V _{O1} -0.1 | V |
| V _{Rth} | Reset Threshold Hysteresis | | 50 | 100 | 200 | mV |
| t _{RD} | Reset Pulse Delay | C _T = 100nF; t _R > 100μs | 55 | 100 | 180 | mV |
| t _{RR} | Reset Reaction Time | C _T = 100nF | 1 | 10 | 50 | μs |
| V _{RL} | Reset Output LOW Voltage | R _{RES} = 10KΩ to V _{O1} V _S = 1.5V | | | 0.4 | V |
| I _{LRES} | Reset Output HIGH Leakage | V _{RES} = 5V | | | 1 | μA |
| V _{CTh} | Delay Comparator Threshold | | | 2.0 | | V |
| V _{CTh, hyst} | Delay Comparator Threshold Hysteresis | | | 100 | | mV |

SENSE

| | | | | | | |
|-------------------------|----------------------------|---|------|------|------|----|
| V _{Slth} | Sense Threshold Voltage | | 1.16 | 1.23 | 1.35 | V |
| V _{Slth, hyst} | Sense Threshold Hysteresis | | 40 | 100 | 200 | mV |
| V _{SOL} | Sense Output LOW Voltage | V _{SI} = 1,16V; V _S ≥ 3V R _{SO} = 10KΩ to V _{O1} | | | 0.4 | V |
| I _{LSO} | Sense Output Leakage | V _{SO} = 5V; V _{SI} ≥ 1.5V | | | 1 | μA |

Note : 1 : V_{O2} connected to ADJ. V_{O2} can be set to higher values by inserting an external resistor divider.
2 : Foldback characteristic

FUNCTIONAL DESCRIPTION

The L4938N is based on the STMicroelectronics modular voltage regulator approach. Several outstanding features and auxiliary functions are provided to meet the requirements of supplying the microprocessor systems used in automotive applications.

Furthermore the device is suitable also in other applications requiring two stabilized voltages.

The modular approach allows other features and functions to be realized easily when required.

STANDBY REGULATOR

The standby regulator uses an Isolated Collector Vertical PNP transistor as the regulating element. This structure allows a very low dropout voltage at currents up to 50mA. The dropout operation of the standby regulator is maintained down to 2V input supply voltage. The output voltage is regulated up to the transient input supply voltage of 40V. This feature avoids functional interruptions which could be generated by overvoltage pulses.

The typical curve of the standby output voltage as a function of the input supply voltage is shown in fig. 1.

The current consumption of the device (quiescent current) is less than 250μA when output 2 is disabled (standby mode). The dropout voltage is controlled to reduce the quiescent current peak in the undervoltage region and to improve the transient response in this region.

The quiescent current is shown in fig. 2 as a function of the supply input voltage 2.

OUTPUT 2 VOLTAGE

The output 2 regulator uses the same output structure as the standby regulator, but rated for an output current of 500mA.

The output 2 regulator works in tracking mode with the standby output voltage as a reference voltage when the output 2 programming pin ADJ is connected to V_{O2}. By connecting a resistor divider R₁, R₂ to the pin ADJ as shown in fig. 3, the output voltage 2 can be programmed to the value :

$$V_{O2} = V_{O1} (1 + R_1/R_2)$$

The output 2 regulator can be switched off via the Enable input.

If a fixed 5 regulation is required ADJ Pin has to be connected to V_{O2} Pin.

Figure 1 : Output Voltage vs. Input Voltage.

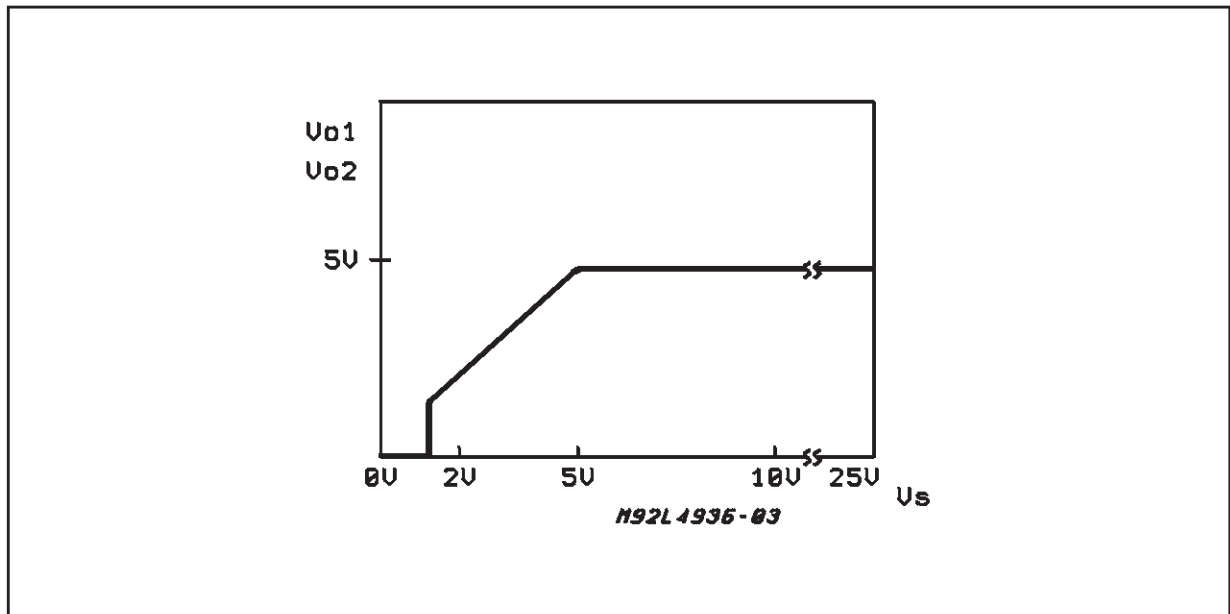


Figure 2 : Quiescent Current vs. Supply Voltage.

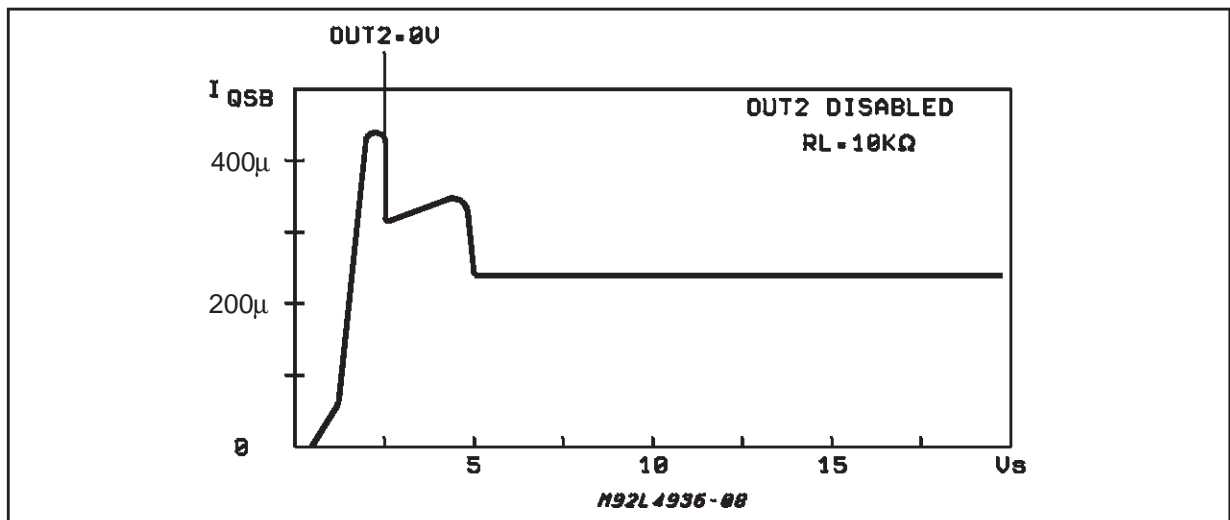
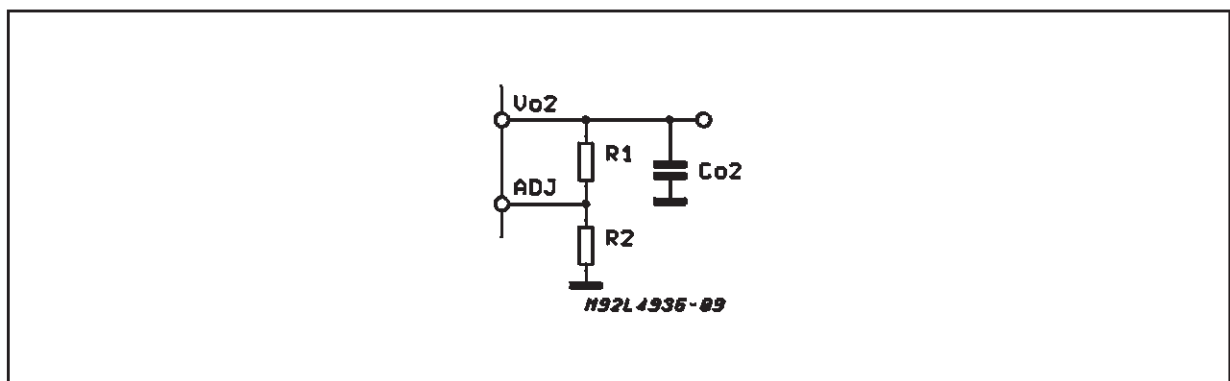


Figure 3 : Programmable Output 2 Voltage with External Resistors.



RESET CIRCUIT

The block circuit diagram of the reset circuit is shown in fig. 4. The reset circuit supervises the standby output voltage. The reset threshold of 4.7V is defined by the internal reference voltage and the standby output divider.

The reset pulse delay time t_{RD} , is defined by the charge time of an external capacitor C_T :

$$t_{RD} = \frac{C_T \times 2V}{2\mu A}$$

The reaction time of the reset circuit depends on the discharge time limitation of the reset capacitor C_T and is proportional to the value of C_T .

The reaction time of the reset circuit increases the noise immunity. In fact, if the standby output voltage drops below the reset threshold for a time shorter than the reaction time t_{RR} , no reset output variation

occurs. The nominal reset delay is generated for standby output voltage drops longer than the time necessary for the complete discharging of the capacitor C_T . This time is typically equal to $50\mu s$ if $C_T = 100nF$. The typical reset output waveforms are shown in fig. 5.

SENSE COMPARATOR

This circuit compares an input signal with an internal voltage reference of typically 1.23V. The use of an external voltage divider makes the comparator very flexible in the application. This function can be used to supervise the input voltage - either before or after the protection diode - and to give additional information to the microprocessor such as low voltage warnings.

If this feature is not used SI and SO have to be connected to GND. In this case the Stand-by quiescent current (14V) increases from $290\mu A$ to $300\mu A$.

Figure 4: Block Diagram of the Reset Circuit.

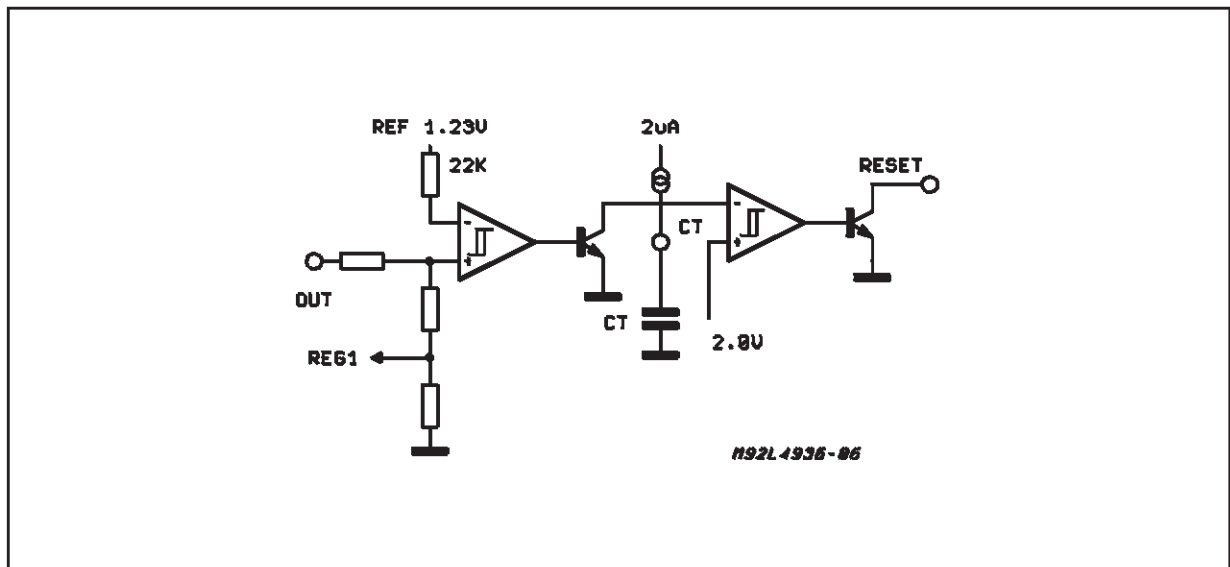
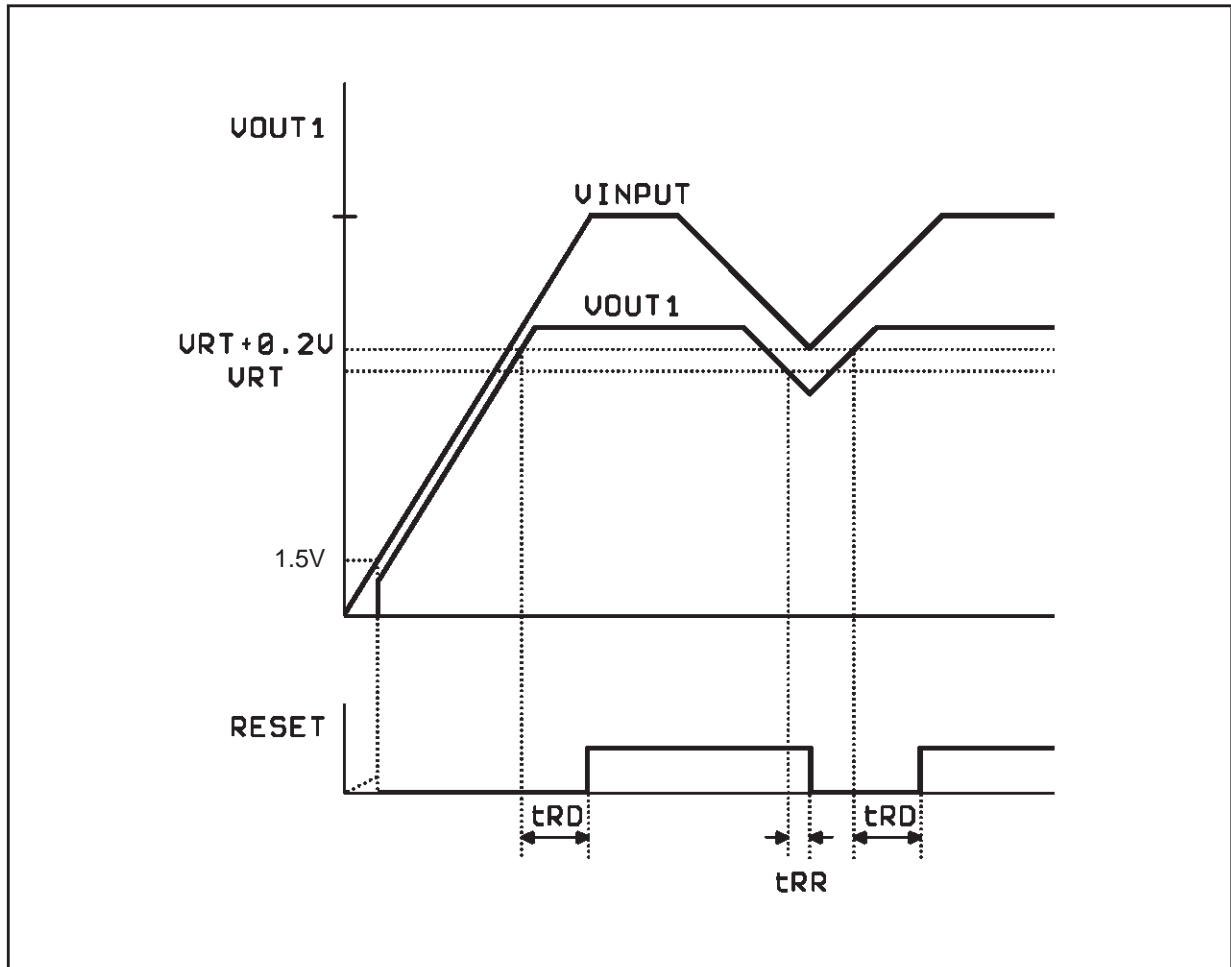
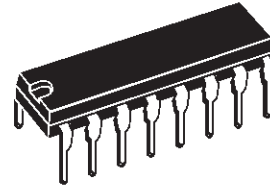


Figure 5 : Typical Reset Output Waveforms.

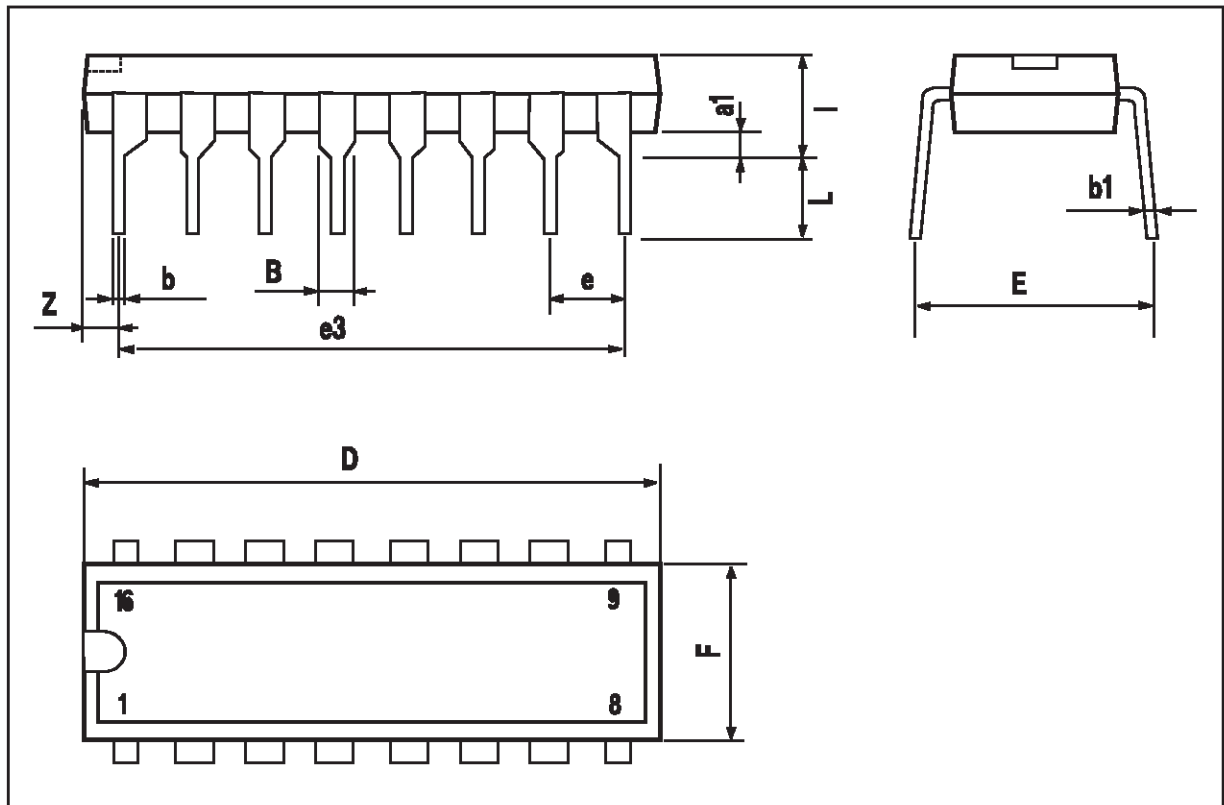


| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| B | 0.85 | | 1.40 | 0.033 | | 0.055 |
| b | | 0.50 | | | 0.020 | |
| b1 | 0.38 | | 0.50 | 0.015 | | 0.020 |
| D | | | 20.0 | | | 0.787 |
| E | | 8.80 | | | 0.346 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 17.78 | | | 0.700 | |
| F | | | 7.10 | | | 0.280 |
| I | | | 5.10 | | | 0.201 |
| L | | 3.30 | | | 0.130 | |
| Z | | | 1.27 | | | 0.050 |

OUTLINE AND MECHANICAL DATA



Powerdip 16

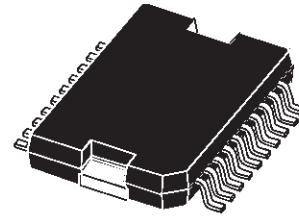


L4938N - L4938ND - L4938NPD

| DIM. | mm | | | inch | | |
|--------|------------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 3.6 | | | 0.142 |
| a1 | 0.1 | | 0.3 | 0.004 | | 0.012 |
| a2 | | | 3.3 | | | 0.130 |
| a3 | 0 | | 0.1 | 0.000 | | 0.004 |
| b | 0.4 | | 0.53 | 0.016 | | 0.021 |
| c | 0.23 | | 0.32 | 0.009 | | 0.013 |
| D (1) | 15.8 | | 16 | 0.622 | | 0.630 |
| D1 | 9.4 | | 9.8 | 0.370 | | 0.386 |
| E | 13.9 | | 14.5 | 0.547 | | 0.570 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 11.43 | | | 0.450 | |
| E1 (1) | 10.9 | | 11.1 | 0.429 | | 0.437 |
| E2 | | | 2.9 | | | 0.114 |
| E3 | 5.8 | | 6.2 | 0.228 | | 0.244 |
| G | 0 | | 0.1 | 0.000 | | 0.004 |
| H | 15.5 | | 15.9 | 0.610 | | 0.626 |
| h | | | 1.1 | | | 0.043 |
| L | 0.8 | | 1.1 | 0.031 | | 0.043 |
| N | 10° (max.) | | | | | |
| S | 8° (max.) | | | | | |
| T | | 10 | | | 0.394 | |

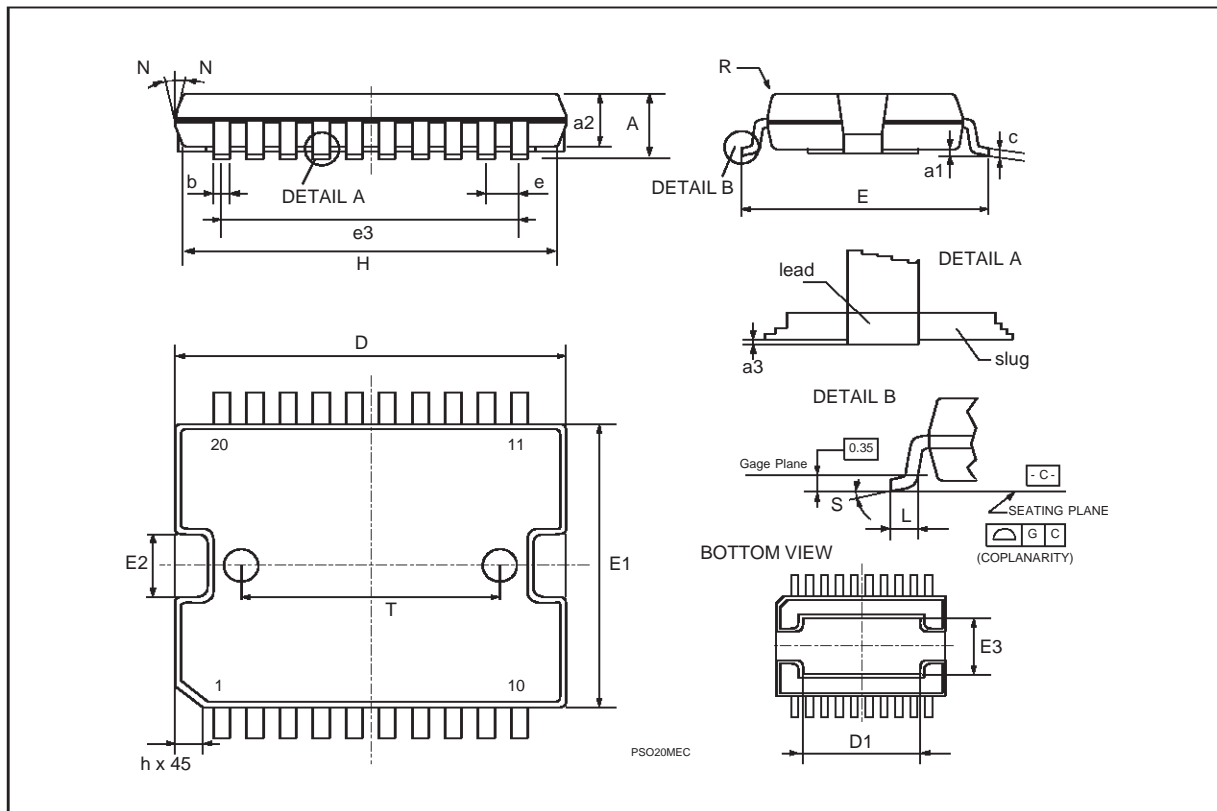
(1) "D and F" do not include mold flash or protrusions.
 - Mold flash or protrusions shall not exceed 0.15 mm (0.006").
 - Critical dimensions: "E", "G" and "a3"

OUTLINE AND MECHANICAL DATA



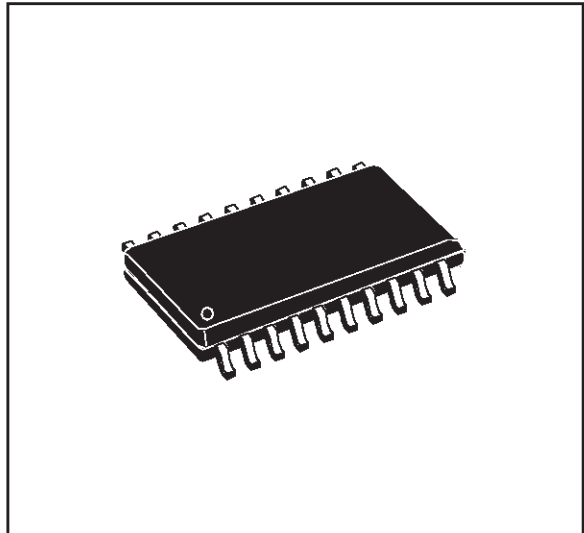
JEDEC MO-166

PowerSO20

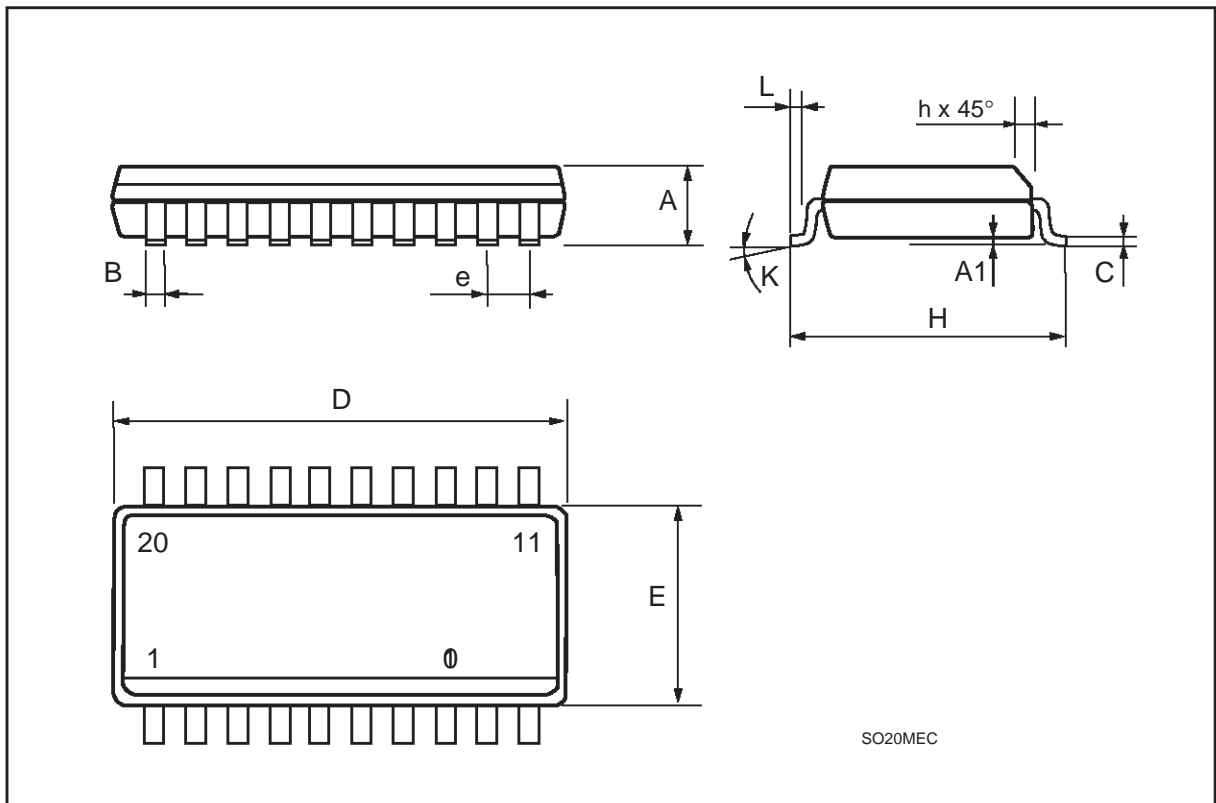


| DIM. | mm | | | inch | | |
|------|---------------------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 2.35 | | 2.65 | 0.093 | | 0.104 |
| A1 | 0.1 | | 0.3 | 0.004 | | 0.012 |
| B | 0.33 | | 0.51 | 0.013 | | 0.020 |
| C | 0.23 | | 0.32 | 0.009 | | 0.013 |
| D | 12.6 | | 13 | 0.496 | | 0.512 |
| E | 7.4 | | 7.6 | 0.291 | | 0.299 |
| e | | 1.27 | | | 0.050 | |
| H | 10 | | 10.65 | 0.394 | | 0.419 |
| h | 0.25 | | 0.75 | 0.010 | | 0.030 |
| L | 0.4 | | 1.27 | 0.016 | | 0.050 |
| K | 0° (min.) 8° (max.) | | | | | |

OUTLINE AND MECHANICAL DATA



SO20



SO20MEC

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